Photonic realization of topologically protected bound states in domain-wall waveguide arrays

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We present an analytical theory of topologically protected photonic states for the two-dimensional Maxwell equations for a class of continuous periodic dielectric structures, modulated by a domain wall. We further numerically confirm the applicability of this theory for three-dimensional structures.

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I. INTRODUCTION

Due to their role as vehicles for localization and transport of energy, surface modes have long been recognized to be of central importance [1,2]. A striking example is that of topologically protected edge states, which were first studied in the quantum Hall effect in condensed matter physics [3–5]. Since 2005, there has been an increasing focus on the protected states of topological insulators [6,7]. More recently, there has also been growing interest in photonic analogues of the topologically protected states observed in electronic systems [8–10]. In particular, such states have been shown to arise via line defects (edges) and time-reversal or spatial-inversion symmetry breaking in linear and nonlinear photonics, e.g., [8,9,11–17].

Theoretical arguments for the existence and robustness of topologically protected edge states have been given in terms of topological invariants associated with the band structure, e.g., the Chern index or Zak phase backed by numerical simulations. A systematic justification of the applicability of such invariants, however, appears only to have been provided in tight-binding models, e.g., [18–21]. In the photonic setting, this corresponds to the limit of infinite medium contrast. We seek a general understanding of topological protection, namely a theory which is applicable outside of limiting regimes, such as the tight-binding or nearly-free-photon approximations. Indeed, many physical settings of interest, including photonics in low contrast periodic structures, fall outside these regimes; see also [13].

In [22,23], a class of one-dimensional (1D) continuous systems described by the Schrödinger equation with a domain-wall modulated (DWM) periodic potential were proved to have topologically protected bound states, originating in the zero-mode of an effective 1D Dirac equation, a mechanism which plays a role in [8,24]; see also [25]. In this paper, we propose and investigate a photonic realization of these states as topologically protected guided wave modes in a class of coupled two-dimensional (2D) waveguide arrays governed by Maxwell’s equations. No tight-binding or nearly-free-photon assumptions are made; the results hold for bulk structures of arbitrary material contrast.

We further demonstrate, through ab initio numerical simulations for the full three-dimensional (3D) Maxwell equations, that these waveguide modes and their properties persist for physically realistic 3D optical waveguide arrays. In particular, robustness against geometric and intrinsic background thermal perturbations is demonstrated. These states have fundamentally linear dispersion and broadband flat group velocity dispersion.

Photonic waveguide array structures are an important class of photonic crystals, providing a natural platform for basic studies of topological insulators and their photonic applications. They permit qualitative study and quantitative measurements of many phenomena [26,27]. Recent work has explored 2D arrays in linear and nonlinear regimes, in both deterministic and random media [28–34].

II. SCHRODINGER SETTING

A. Guided TM Maxwell modes as eigenmodes of the Schrödinger equation

The propagation of light in space, with coordinates (x,y,z), in a dielectric medium with constant permeability and permittivity depending on only one variable ε(x) is governed by Maxwell’s equations. Time-harmonic modes, which propagate in the z-waveguided direction are of transverse-electric (TE) (E1,H,E2) or transverse-magnetic (TM) (H1,E,H2) type. We focus on the TM case; an analogous discussion holds for TE modes.

TM modes with frequency ω, which are localized in the transverse x direction, are of the form

\[ E(x,z,t) = e^{iωt} e^{ikx} \xi(z) \frac{\omega}{c}\Psi \left( \frac{\omega}{c} x \right), \] (1)

where (μ,Ψ(x')) is a solution of the Schrödinger eigenvalue problem (EVP) with potential −ε(z) and energy
\[\mu = -\frac{\omega}{\mu} k_z^2;\]
\[\left(-\frac{\partial^2}{\partial x^2} - \frac{1}{\mu} \left(\frac{e}{c} x'\right)\right) \Psi(x') = \mu \Psi(x'), \quad \Psi \in L^2(\mathbb{R}). \quad (2)\]

Here, \(e(x')\) denotes the guided mode effective permittivity as a function of the dimensionless transverse distance \(x' = \frac{x}{\sqrt{\epsilon}}\), \(k_z\) is the \(z\)-propagation constant, and \(c\) is the vacuum speed of light. If \((\mu, \Psi)\) is an eigenpair of (2) for which \(k_z^2 = -\omega^2/c^2 \mu > 0\), then \(k_z\) is real and (1) is a guided TM mode, propagating in \(z\) and localized in \(x\).

### B. Topologically protected bound states

In [22,23], the authors study topologically protected bound states in 1D domain-wall modulated (DWM) Schrödinger Hamiltonians of the form: \(H^0 = -\partial_x^2 + V(x) + \delta \kappa(x) W(x)\), where \(V\) and \(W\) denote even-index and odd-index cosine series, respectively; and \(\kappa(x)\) is a so-called domain-wall function that satisfies \(\kappa(x) \to \pm \infty\) as \(x\to \pm \infty\). The Floquet-Bloch EVPs \(H^0\Phi(x; k_x) = E \Phi(x; k_x)\), \(\Phi(x+1; k_x) = e^{i\kappa x} \Phi(x; k_x)\), parametrized by \(k_x \in [0, 2\pi]\), possess Dirac points. These are pairs \((k_x, \pi, E)\).

**Theorem 1** ([22,23]). The Floquet-Bloch EVPs for \(H^0 = -\partial_x^2 + V(x); H^0\Phi(x; k_x) = E \Phi(x; k_x), \Phi(x+1; k_x) = e^{i\kappa x} \Phi(x; k_x)\), parametrized by \(k_x \in [0, 2\pi]\), possess Dirac points. These are pairs \((k_x, \pi, E)\).

**C. Protected vs nonprotected modes**

To contrast the protected modes of DWM structures with conventional nonprotected modes of periodic structures with defects which arise via bifurcations from a band-edge energy \(E_k(k_{\text{edge}})\), consider the Hamiltonian \(h^0 = -\partial_x^2 + V(x) + \delta \kappa(x) W(x) + \delta^2 G(\delta x)\), which incorporates both a domain-wall induced phase defect \(\delta \kappa(x) W(x)\) and a localized defect \(\delta^2 G(\delta x)\); scalings are chosen so that both effects are of comparable size. Band-edge bifurcations are seeded by band states of the effective Schrödinger operator \(h_{b,\text{eff}} = -\partial_x^2 + V(x) + \delta \kappa(x) W(x) + \delta^2 G(\delta x)\), with effective mass \([35] m_{b,\text{eff}} = E_k(k_{\text{edge}})\) and effective potential \(Q_{b,\text{eff}}(x) = c_b [\kappa_{\text{edge}}^2 - \kappa^2(x)] + G(x)\), \(c_b > 0\). While the zero-energy eigenstate of \(D\), which induces the bifurcation of bound states from a Dirac point [2], persists under arbitrary (even large) localized perturbations of the domain wall \(\kappa(x)\), the localized states of \(h_{b,\text{eff}}\), and therefore their induced branch of bound states [1], are not stable to arbitrary localized perturbations \(G(x)\) [36,37].

In Fig. 1(c), where \(G \equiv 0\), the domain wall induces bifurcations from Dirac points as well as from band edges. In Fig. 1(d), a nonzero localized perturbation \(G(x)\) has destroyed the lower band edge bifurcation; the edge bifurcation can be removed by smooth deformation of \(h^0\) while the Dirac point bifurcation is topologically protected. The protected states of DWM structures also exhibit a remarkable robustness of their eigenvalues (operating or working frequencies) when compared with those of conventional...
structures with localized defects. To illustrate this, we extend the previous model to a Hamiltonian \( h^D = -\nabla_x^2 + V_c(x) + \delta \xi \gamma x \), with defect mode eigenvalue \( E^D_k \), where changing \( \gamma \) varies the phase defect’s transition region width (where \( \kappa \) transitions between positive to negative values) and the area of the localized defect \( G \). The potential in \( h^D \) is assumed to be smooth. For \( \gamma \approx 1 \) and \( \delta \ll 1 \), \( E^D_k \) of the order \( (\Delta E)_G \approx (\gamma - 1) \delta \Gamma \). For \( \delta \ll 1 \), we have \( \Psi^D_x \approx \delta \frac{1}{2} e^{-c|\Delta k|} \), \( c > 0 \); see Theorem 2 and [22, 37]. Therefore, using the rapid oscillations of \( W_0(y/\delta) \), we have \( (\Delta E)^D_x \approx (\gamma - 1) \delta \Gamma \) for all \( M \in \mathbb{Z}^+ \) where \( F(y) = \Gamma(y)e^{-2\delta y} \). On the other hand, a direct computation gives \( (\Delta E)_G \approx O((\gamma - 1) \delta \Gamma) \). Hence, for small \( \delta \) and \( \gamma \approx 1 \), we have \( |(\Delta E)_G| \ll |(\Delta E)^D_x| \). Numerical simulations for larger \( \delta \) and \( \gamma \ll 1 \) further corroborate the strong robustness of the operating frequency of topologically protected modes; see Fig. 2.

III. MAXWELL SETTING

A. 2D topologically protected, guided TM modes

Returning to the Maxwell setting, Theorem 2 and (1) imply:

Corollary 1. Maxwell’s equations exhibit topologically protected, transversely localized, guided TM modes.

We realize these topologically robust TM modes in a photonic waveguide array by constructing a coupled 2D silicon-air waveguide array profile \( \varepsilon_x(x) \) corresponding to a potential \( U_c(x) \). We construct \( U_c(x) \) to be the two-valued approximation of a choice of \( V_c(x) + \delta \xi \gamma x \), scaled to match the effective permittivities of silicon (12.1) and air (1). \( U_{c=0}(x) \) is the DWM structure and \( U_{c=1}(x) \) is the periodic potential having Dirac points. Finally, we set \( \varepsilon_x(\pm \pi/a) = -\varepsilon_x(x) \); see (2). The 2D DWM waveguide array is shown in Fig. 3(b). Although the relative length scale between \( U_c(x) \) and \( \varepsilon_x(x) \) is important, the computations may be carried out at arbitrary length scales due to the scale invariance of Maxwell’s equations [12].

Since the numerically computed lowest energy gap mode of the Schrödinger equation with the DWM potential \( U_{c=1}(x) \) satisfies \( \mu < 0, k_z = \pm \omega a) \) is real and the corresponding TM mode in (1) is guided.

The dispersion curves \( k_z \leftrightarrow \omega(k_z) \) for TM modes of the 2D periodic (unmodulated) structure \( \varepsilon_{c=0}(x) \) are displayed in Fig. 3(c). These curves are computed by solving the 2D Maxwell equations for \( \omega \) at discrete \( k_z \) values, using MPB [38]. The dispersion curves \( k_z \leftrightarrow \omega(k_z) \) for the DWM waveguide \( \varepsilon_{c=1}(x) \) are displayed in Fig. 3(e). In analogy with the Schrödinger setting, robust guided modes are observed in gaps about Dirac points at quasimomentum \( k_z = \pi a \), where \( k_z \) is the lattice constant; see Figs. 1(a) and 1(b). Qualitatively similar dispersion curves are observed for TE modes.

We numerically study on-axis \( z \) propagation in the DWM 2D waveguide of a Gaussian wave-packet, using the approximate paraxial Schrödinger equation [39, 40]. For the periodic array, the energy of the launched packet quickly delocalizes [Fig. 4(a)]. In contrast, in the DWM structure, a topologically protected mode is excited and

FIG. 2. Greater robustness of the operating frequency of protected modes when compared with conventional nonprotected modes, illustrated by the spectra of \( h^D = -\nabla_x^2 + V_c(x) + \delta \xi \gamma x \). Finally, we set \( \varepsilon_x(\pm \pi/a) = -\varepsilon_x(x) \); see (2).

FIG. 3. 2D Maxwell problem. (a) Periodic \( (\delta = 0) \) 2D silicon-air waveguide array with lattice constant (period) \( a \). (b) DWM \( (\delta = 1) \) 2D silicon-air array. Left and right asymptotic 2\( \gamma \) periods are phase shifted relative to one another. Modulated structures consisting of five waveguide channels (three shown here) on either side of the defect region were used for numerical computations. (c) TM dispersion curves \( \omega(k_z) \) (gray) and frequency spectra (black) of the first few TM bands of the periodic 2D waveguide array \( (\delta = 0) \), with \( k_z = 2\pi a / 10 \) fixed. Linear band crossings (Dirac points) occur at \( k_z = \pi a \). (d) For the 2D DWM waveguide array \( (\delta = 1) \), bound state energies (red dot) bifurcate into spectral gaps about Dirac points of the periodic (unmodulated) structure. (e) Dispersion curves \( \omega(k_z) \) of the first few TM bands for the 2D DWM waveguide. Eigenvalue curves (red), corresponding to guided modes, lie in between bands of continuous spectrum (black).
confinest most of the energy on-axis [Fig. 4(b)]. A quantitative
comparison of localization properties of the DWM and
periodic structures is obtained by measuring \( \xi \), the fraction of
power remaining within (roughly) the width of the profile of the
stationary localized mode of the DWM structure at \( z = 50a \):
\[
\xi = \frac{\| E(x,z = 50a) \|_{L^2([-5a,5a])}}{\| E(x,z = 0) \|_{L^2([-30a,30a])}}.
\]
The DWM structure achieves significantly more localization:
\( \xi_{\text{DWM}} = 0.92 \) and \( \xi_{\text{periodic}} = 0.35 \).

**B. 3D topologically protected, guided TM modes**

The theory summarized in Theorem 2 and Corollary 1
is exact and rigorous for a 2D waveguide with effective
permittivity satisfying \( \varepsilon = \varepsilon(x) \). The physical 3D DWM
waveguide is a finite height \( \varepsilon \) truncation of the 2D structure.
Numerical simulations (below) show a long lived 3D state,
localized in the \( x \) direction even for small height truncations.
A schematic of a 3D silicon waveguide (effective permittivity
12.1) with height 0.25\( a \) and silicon-dioxide cladding (effective
permittivity 2.085) is shown in Fig. 5(b).

Numerically computed dispersion curves: \( k_z \mapsto \omega(k_z) \), for
TM modes of the 3D DWM waveguide, are displayed in Fig. 5(e).
From \( \omega(k_z) \), we compute the group velocity dispersion (GVD),
\( \partial^2 k_z / \partial \omega^2 \); see figure inset.

Corollary 1 ensures that the 2D TM modes, which bifurcate
from Dirac points, are topologically stable. We confirm the
existence and persistence of their 3D counterparts through a
computational study of two classes of physical perturbations:
(i) changes in the effective permittivity due to thermal
fluctuations; and (ii) geometric perturbations in the lattice
constants (waveguide channels) of the array due to fabrication
imperfections, both 10\% perturbations, randomly sampled
from a uniform distribution. Figure 5(d) (solid) displays the
mean deviation of the GVD curves of perturbed waveguides
relative to the unperturbed (DWM) waveguide, calculated
from 100 independent simulations. Also plotted (dotted),
for reference, are the corresponding mean relative deviation of the
GVD curves for a regular channel silicon-silicon
dioxide waveguide (of height 0.25\( a \) and channel width 0.45\( a \)).
GVD robustness of topologically protected DWM guided
modes, with respect to thermal and geometric perturbations,
is comparable to that for regular channel modes.

Fixing \( \omega = 4.0c/\lambda \), we also observe that the mode itself
remains localized against the perturbations, as measured by the
perturbed effective mode area statistics [41]: \( A_{\text{thermal}} = 0.92 \pm 0.09 \) and \( A_{\text{geometric}} = 0.9 \pm 0.4 \). Here the perturbed
mode areas are normalized against the unperturbed mode area,
and reported as means with corresponding standard deviations,
calculated from 50 independent simulations.

**IV. CONCLUSION**

Summarizing, building upon the theory of [22,23], we
have demonstrated the bifurcation of highly robust guided
TM modes for Maxwell’s equations governing a class of
domain-wall modulated photonic waveguide arrays in two dimensions. Our findings are corroborated by full Maxwell simulations of physically realistic 3D structures, derived from our 2D model. In contrast to the guided wave modes of conventional waveguides, domain-wall modulated modes are robust to large localized perturbations while having comparable GVD robustness characteristics. These topologically protected states may be well suited for chip-scale nanofabrication of semiconductor waveguides for communications and frequency source generation.

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